# Hybrid 6p111 Traveler

January 11, 2000

## 1 Connectivity

Repairs on shorts:

Fixes for opens: Bus 3B open on chip 3; jumped from chip 2.

## 2 Chips

The following chips were assembled on this hybrid (in the order that the chips get read out):
Hybrid 6P111 has die: 195-095 195-096 195-097 195-098 195-103 195-104

## 3 Data Analysis Summary

The following summarizes the findings of the Burn-in data analysis program. The first chip in the readout name is numbered 0.

```
% Hybrid 6p111 classification info. Created 12:18:45 01/10/00

Hybrid 6p111 quality: fair
Chip classification: good good good good fair good
Bad channels (chip-channel): 4-87
Bad cells: none
Random bad capacitors: none
Channels at pedestal needed for DCMS: 32.6 32.7 35.6 34.6 38.5 37.6
```

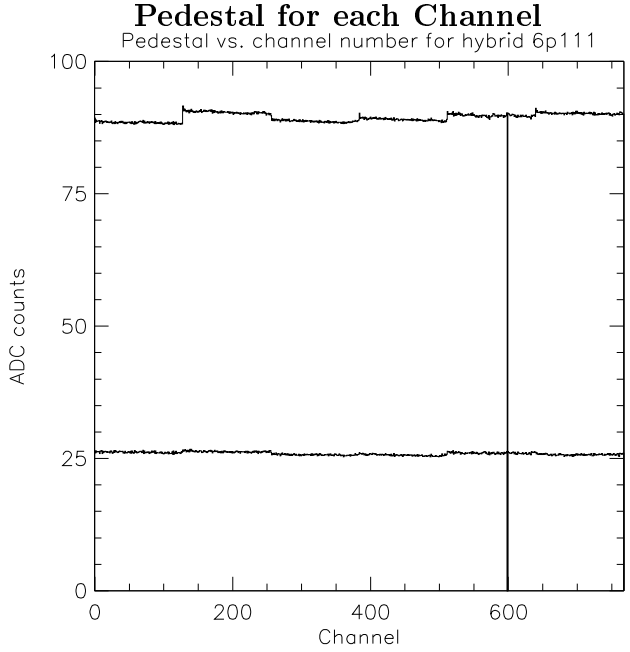
## 4 Comments

Has Au FE DVDD, DGND bonds.
HV test.

# 5 Pedestal

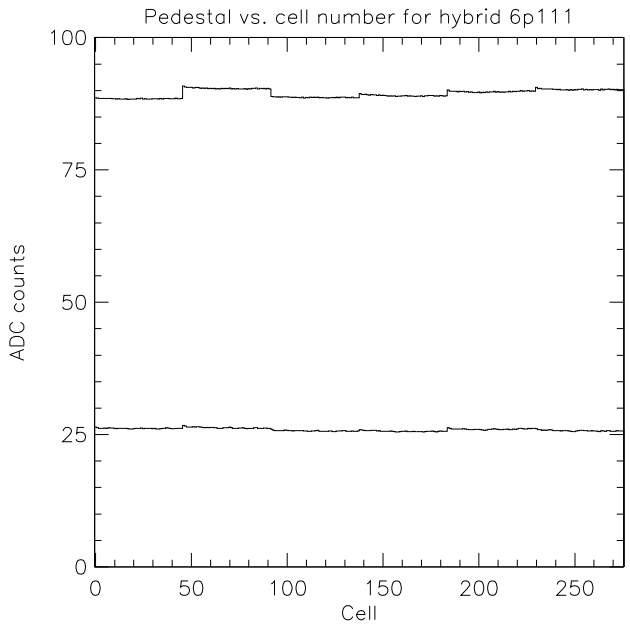
The following plot shows the pedestals vs. channel number with and without charge injection:

**Pedestal for each Channel**




The following plot shows the average pedestal vs. pipeline cell ID with and without charge injection. The x-axis is cell ID offset by 46 for each chip. Thus cell ID 5 for chip 1 is at x=5, chip 2 at x=51, chip 3 at x=97, etc.

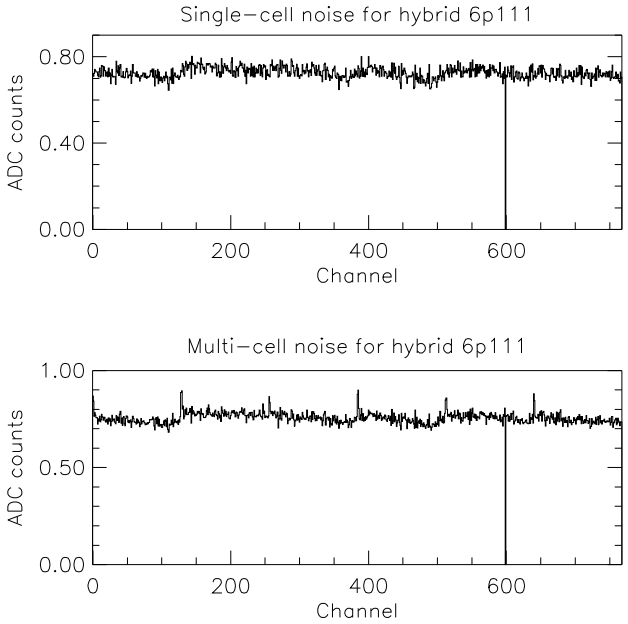
**Pedestal vs. Pipeline Cell ID**



# 6 Noise

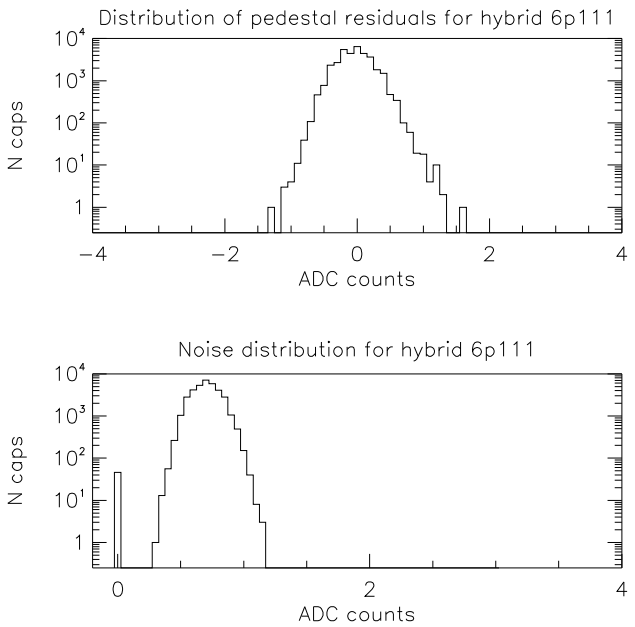
The following plots show the single-cell and multi-cell RMS noise:

**RMS Noise**

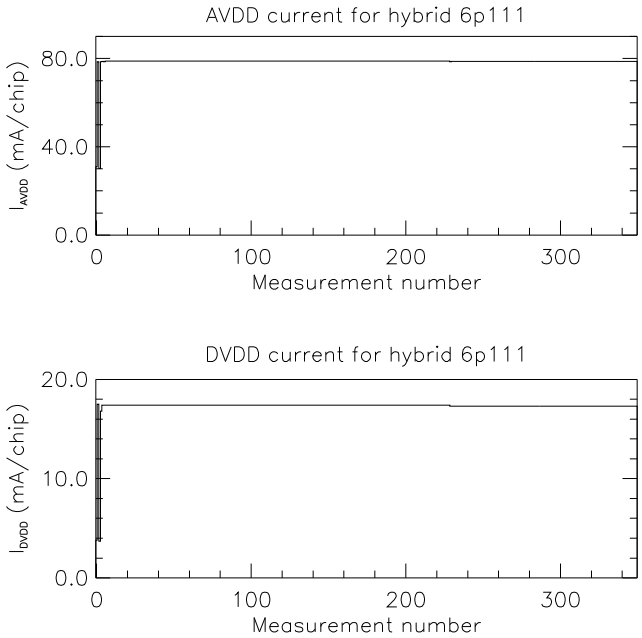



The following are histograms of the pedestal of each pipeline capacitor relative to the chip average (top); and the RMS noise of each capacitor (bottom):

**Distribution of Pedestals and Noise**



# 7 Currents

The following plots show the supply currents per chip as a function of measurment number. Currents are measured approximately every 10 minutes:

**Supply Currents During Burn-in**